

## Exercise 3- Solution

1- From figure 3:  $R_{DS(on)} = 1.02 * R_{DS(Nom)}$  when  $I_D = 12 \text{ A}$ , and  $T_j = 25 \text{ }^\circ\text{C}$

From numerical values  $R_{DS(ON)} = 0.5 \text{ ohms}$  then  $R_{DS(ON)} = 1.02 * 0.5 = 0.51 \text{ ohms}$ .

Symbol	Test Conditions	Characteristic Values ( $T_j = 25^\circ\text{C}$ , unless otherwise specified)			Applications
		min.	typ.	max.	
$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	600			V
$V_{DS(VM)}$	$V_{GS} = V_{GS}, I_D = 4 \text{ mA}$		2.0		4.5 V
$I_{DSS}$	$V_{GS} = \pm 20 \text{ V}_{DC}, V_{DS} = 0$			$\pm 100$	nA
$I_{DSS}$	$V_{GS} = 0.8 * V_{DSS}, V_{GS} = 0 \text{ V}$	$T_j = 25^\circ\text{C}$		250	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$		1	mA
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 0.5 * I_{DSS}$ Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2\%$	15N80 20N80		0.50 0.35	$\Omega$

**Applications**

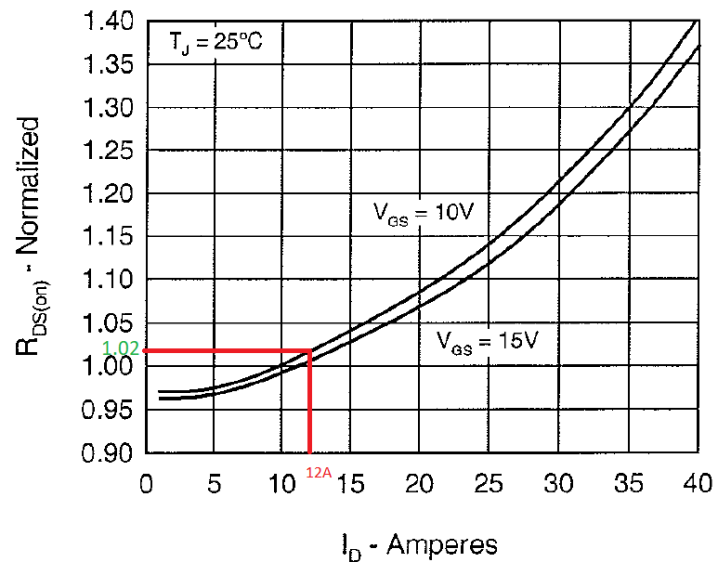
- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls
- Low voltage relays

**Advantages**

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- Space savings
- High power density

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Fig. 3  $R_{DS(on)}$  vs. Drain Current



From figure 4 @ temperature  $T_j = 150^\circ\text{C}$  Thermal coefficient is 2.2 then:

$$R_{DS(ON)} = 2.2 * R_{DS} = 2.2 * 0.51 \text{ ohms} = 1.12 \text{ ohms}$$

Conduction loss energy can be written as:

$$E_h = R_{DS} * I_D^2 * t_{on} = 1.12 * (12 \text{ A})^2 * 20 \mu\text{s} = 3.23 \text{ mJ}$$

Switching losses are not given in the datasheet. We may use triangular model based on rise and fall times. Assuming that voltage is constant and current is changing linearly. Therefore switching energy is:

$$E_{h_{on}} = t_r * U_{DS_{on}} * I_D / 2 = 60 \text{ ns} * 360 \text{ V} * 12 \text{ A} / 2 = 0.13 \text{ mJ}$$

Similarly for turn off losses:

$$E_{h_{off}} = t_f * U_{DS_{off}} * I_D / 2 = 60 \text{ ns} * 500 \text{ V} * 12 \text{ A} / 2 = 0.18 \text{ mJ}$$

Given  $F_{sw} \gg 1 \text{ kHz}$  we may assume steady state thermal resistance and average loss power. For lower frequencies, use figure 10.

$$P_{h_{avg}} = ( E_h + E_{h_{on}} + E_{h_{off}} ) / T = (3.23 \text{ mJ} + 0.13 \text{ mJ} + 0.18 \text{ mJ}) / 40 \mu\text{s} = 88.5 \text{ W}$$

## Power Electronics Components

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Cooling element surface temperature:

$$T_h = T_{jmax} - (R_{th(j-c)} + R_{th(c-k)}) * P_{h\_avg} = 150^\circ \text{C} - (0.42 \text{ K/W} + 0.25 \text{ K/W}) * 88.5 \text{ W} = 90.7^\circ \text{C}$$

Cooling element thermal resistance must be less than

$$R_{th(h-a)} < (T_h - T_a) / P_{avg} = (90.7^\circ \text{C} - 45^\circ \text{C}) / 88.5 \text{ W} = 0.52 \text{ K/W}$$

2- Losses as a function of thermal resistance coefficient

$$P_{h\_avg} = P_{sw} + P_{conduction}$$

$$= (E_{h\_on} + E_{h\_off})/T + r_{ds}(T_j) * R_{DS(l_d)} * I_d^2 * t_{conduction} / T$$

$$= (0.13 \text{ mJ} + 0.18 \text{ mJ}) / 40 \text{ us} + r_{ds}(T_j) * (0.51 \text{ ohm}) * (12 \text{ A})^2 * 20 \text{ us} / 40 \text{ us}$$

$$= 7.75 \text{ W} + r_{ds}(T_j) * 36.7 \text{ W}$$

Now we have a line equation between  $P_h$  and  $T_j$  and we need to another describing line for the cooling system.

$$P_{cool} = T_j - T_a / (R_{th(j-c)} + R_{th(c-k)} + R_{th(h-a)}) = (T_j - 45^\circ \text{C}) / (0.42 + 0.25 + 0.52 \text{ K/W}) = T_j / 1.19 \text{ K/W} - 37.8 \text{ W}$$

